

# 1A, 50V - 600V Surface Mount Ultrafast Power Rectifier

#### **FEATURES**

- Glass passivated chip junction
- Ideal for automated placement
- Ultrafast recovery time for high efficiency
- Low forward voltage, low power loss
- Compliant to RoHS Directive 2011/65/EU and in accordance to WEEE 2002/96/EC
- Halogen-free according to IEC 61249-2-21

KEY PARAMETERS					
PARAMETER	VALUE	UNIT			
I <sub>F(AV)</sub>	1	Α			
$V_{RRM}$	50 - 600	>			
T <sub>J MAX</sub>	175	°C			
Package	DO-214AA (SMB)				
Configuration	Single Die				

#### **APPLICATIONS**

- Switching mode power supply (SMPS)
- Adapters
- Lighting application
- Converter

#### **MECHANICAL DATA**

- Case: DO-214AA (SMB)
- Molding compound meets UL 94V-0 flammability rating
- Moisture sensitivity level: level 1, per J-STD-020
- Packing code with suffix "G" means green compound (halogen-free)
- Part no. with suffix "H" means AEC-Q101 qualified
- Terminal: Matte tin plated leads, solderable per J-STD-002
- Meet JESD 201 class 2 whisker test
- Polarity: As marked
- Weight: 0.09 g (approximately)





DO-214AA (SMB)

ABSOLUTE MAXIMUM RATINGS (T <sub>A</sub> = 25°C unless otherwise noted)								
PARAMETER	SYMBOL	MUR	MUR	MUR	MUR	MUR	MUR	UNIT
	01111202	105S	110S	115S	<b>120S</b>	<b>140S</b>	160S	
Marking code on the device		MUR	MUR	MUR	MUR	MUR	MUR	
Marking code on the device		105S	110S	115S	120S	140S	160S	
Repetitive peak reverse voltage	$V_{RRM}$	50	100	150	200	400	600	V
Reverse voltage, total rms value	$V_{R(RMS)}$	35	70	105	140	280	420	V
Maximum DC blocking voltage	$V_{DC}$	50	100	150	200	400	600	V
Forward current	I <sub>F(AV)</sub>	1				Α		
Surge peak forward current, 8.3 ms single half sine-wave superimposed on rated load per diode	I <sub>FSM</sub>	40 35		5	А			
Junction temperature	T <sub>J</sub>	- 55 to +175			°C			
Storage temperature	T <sub>STG</sub>	- 55 to +175			°C			



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THERMAL PERFORMANCE			
PARAMETER	SYMBOL	LIMIT	UNIT
Junction-to-lead thermal resistance	$R_{\Theta JL}$	17	°C/W

PARAMETER	CONDITIONS	SYMBOL	TYP	MAX	UNIT	
	MUR105S		V <sub>F</sub>	-	0.875	V
	MUR110S					V
Forward voltage per diode (1)	MUR115S	   I <sub>F</sub> = 1Α,Τ <sub>J</sub> = 25°C				V
i oiwaid voitage per diode	MUR120S	1; - 17, 1 j - 25 O				V
	MUR140S			_	1.250	V
	MUR160S					V
	MUR105S					V
	MUR110S		$V_{F}$	-	0.710	V
Forward voltage per diode (1)	MUR115S	I <sub>F</sub> = 1A,T <sub>J</sub> = 150°C			1.050	V
•	MUR120S					V
	MUR140S MUR160S			-		V
		- - - T <sub>J</sub> = 25°C	I <sub>R</sub>	-	2	
Reverse current @ rated $V_R$ per diode $^{(2)}$	MUR105S					μΑ
	MUR110S					μA
	MUR115S					μA
	MUR120S			-	5	μA
	MUR140S					μA
	MUR160S					μA
	MUR105S		I <sub>R</sub>	-	50 150	μA
	MUR110S					μA
Reverse current @ rated V <sub>R</sub>	MUR115S	T <sub>J</sub> = 150°C				μA
per diode (2)	MUR120S					μA
	MUR140S					μA
	MUR160S					μA
	MUR105S		t <sub>rr</sub>	-	25	ns
	MUR110S	I <sub>F</sub> =0.5A ,I <sub>R</sub> =1.0A				ns
	MUR115S					ns
Reverse recovery time	MUR120S					ns
	MUR140S			-	50	ns
	MUR160S					ns

## Notes:

- 1. Pulse test with PW=0.3 ms
- 2. Pulse test with PW=30 ms



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ORDERING INFORMATION							
PART NO.	PART NO. SUFFIX	PACKING CODE	PACKING CODE SUFFIX(*)	PACKAGE	PACKING		
		R5		SMB	850 / 7" Plastic reel		
MUR1xxS (Note 1)	Н	R4	G	SMB	3,000 / 13" Paper reel		
(1.1310-1)		M4		SMB	3,000 / 13" Plastic reel		

#### Note:

<sup>\*:</sup> Optional available

EXAMPLE P/N					
EXAMPLE P/N	PART NO.	PART NO. SUFFIX	PACKING CODE	PACKING CODE SUFFIX	DESCRIPTION
MUR160SHR5G	MUR160S	Н	R5	G	AEC-Q101 qualified Green compound

<sup>1. &</sup>quot;x" defines voltage from 50V (MUR105S) to 1000V (MUR160S)



### **CHARACTERISTICS CURVES**

 $(T_A = 25^{\circ}C \text{ unless otherwise noted})$ 

Fig1. Forward Current Derating Curve

1.5 VERYARD CURRENT (°C)

Fig2. Typical Junction Capacitance

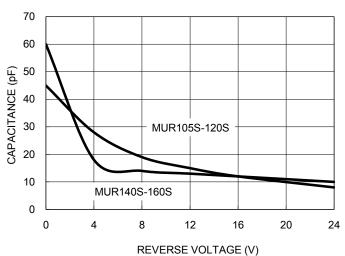


Fig3. Typical Reverse Characteristics

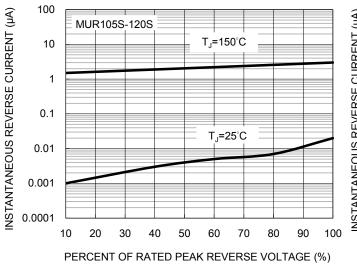
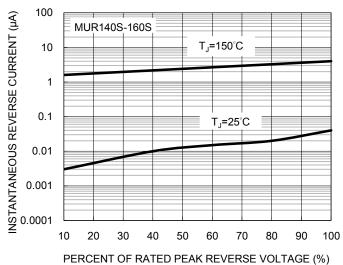


Fig4. Typical Reverse Characteristics



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Fig5. Typical Forward Characteristics

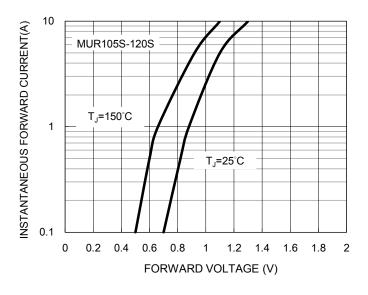


Fig6. Typical Forward Characteristics

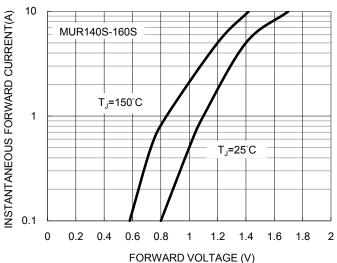
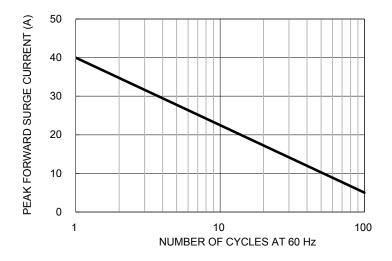


Fig5. Maximum Non-repetitive Forward Surge Current

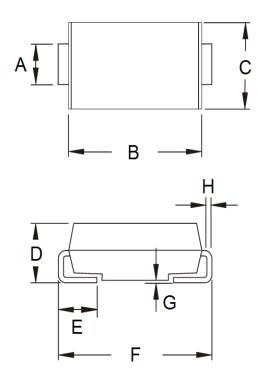


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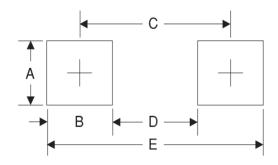
## **PACKAGE OUTLINE DIMENSIONS**

DO-214AA (SMB)



DIM.	Unit	(mm)	Unit (inch)		
DIIVI.	Min Max		Min	Max	
Α	1.95	2.20	0.077	0.087	
В	4.05	4.60	0.159	0.181	
С	3.30	3.95	0.130	0.156	
D	1.95	2.65	0.077	0.104	
Е	0.75	1.60	0.030	0.063	
F	5.10	5.60	0.201	0.220	
G	0.05	0.20	0.002	0.008	
Н	0.15	0.31	0.006	0.012	

## **SUGGESTED PAD LAYOUT**



Symbol	Unit (mm)	Unit (inch)
А	2.3	0.091
В	2.5	0.098
С	4.3	0.169
D	1.8	0.071
E	6.8	0.268

### **MARKING DIAGRAM**



P/N = Marking Code
G = Green Compound
YW = Date Code
F = Factory Code



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